

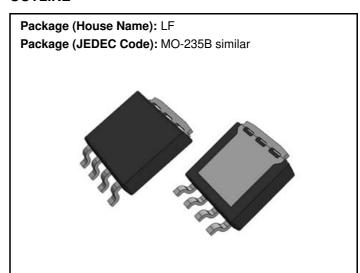
P38LF6QN

Power MOSFETs 60V, 38A, N-channel

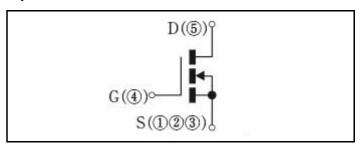
Feature

- N-channel
- · Small SMD
- Low Ron
- 10V Gate Drive
- Low Capacitance
- · Halogen free
- · Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 175	°C
Channel tempertature	Tch		-55 to 175	°C
Drain-source voltage	V_{DSS}		60	V
Gate-source voltage	V_{GSS}		±20	V
Continuous drain current(DC)	I _D		38	Α
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	114	Α
Total power dissipation	P _T		123	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	22	Α
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	57	mJ

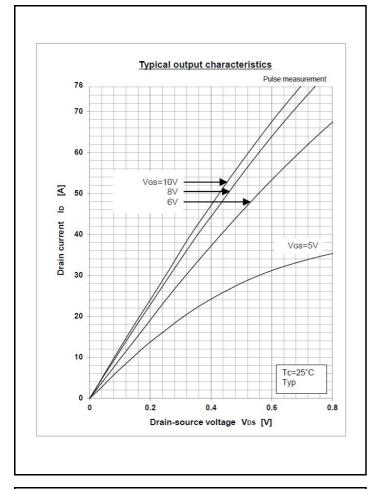
^{* :} See the original Specifications

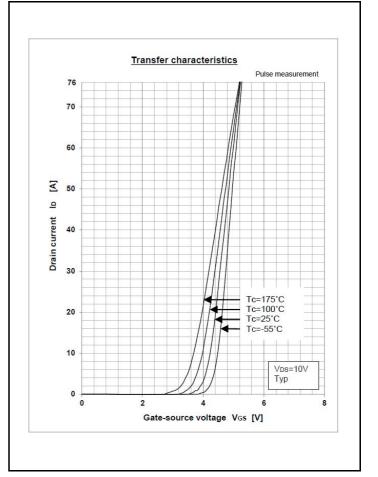
Electrical Characteristics (unless otherwise specified : Tc=25°C)

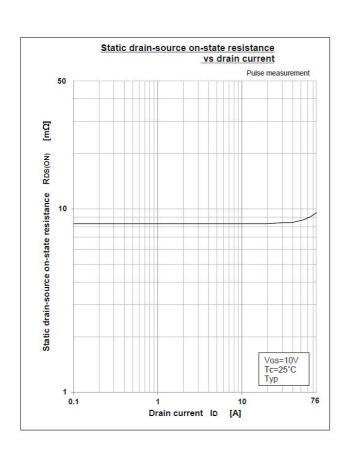
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	Oilit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	60			٧
Zero gate voltage drain current	I _{DSS}	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	9fs	ID=19A, VDS=10V	8.5			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=19A, VGS=10V		0.0083	0.0104	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=38A, VGS=0V			1.5	٧
Thermal resistance	Rth(j-c)	Junction to case, with heatsink			1.21	°C/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=38A		35		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=38A		11		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=38A		11		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		1875		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		90		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		209		pF
Turn-on delay time	td(on)	ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		5		ns
Rise time	tr	ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		5.5		ns
Turn-off delay time	td(off)	ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		19		ns
Fall time	tf	ID=19A, RL=1.5Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		5		ns
Diode reverse recovery time	trr	IF=38A, VGS=0V, di/dt=100A/μs		39		ns
Diode reverse recovery charge	Qrr	IF=38A, VGS=0V, di/dt=100A/μs		40		nC

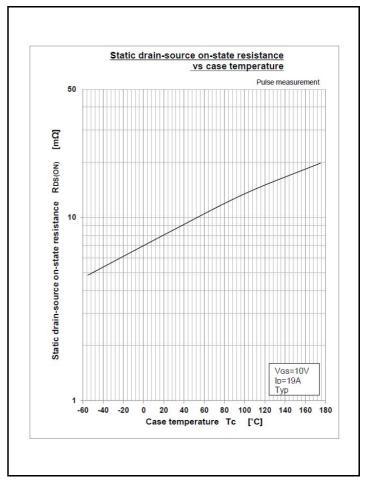
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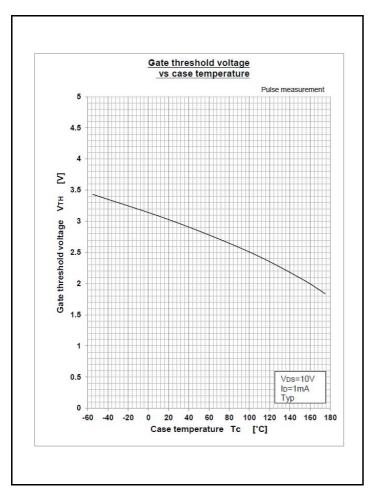
CHARACTERISTIC DIAGRAMS

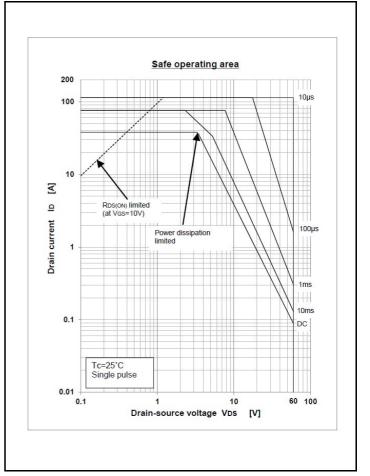


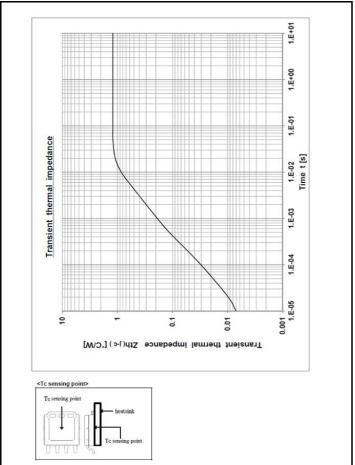


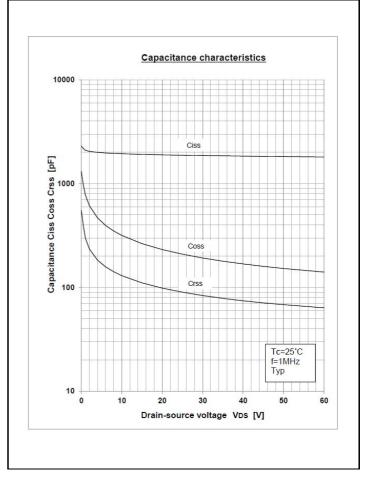


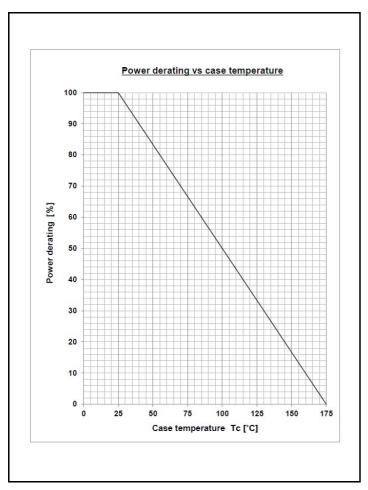


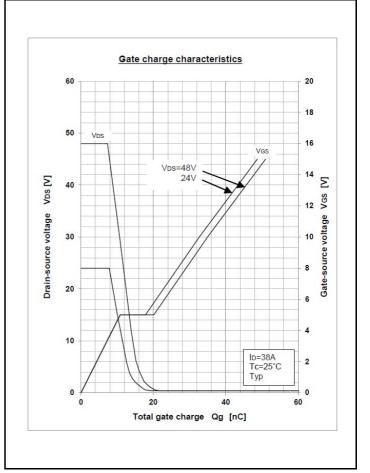


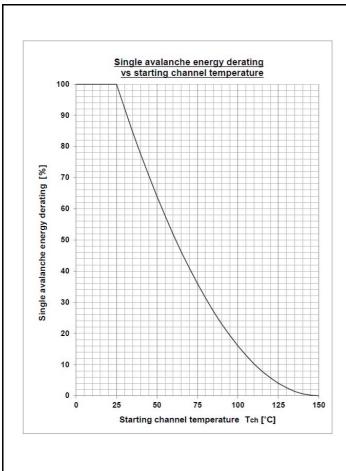




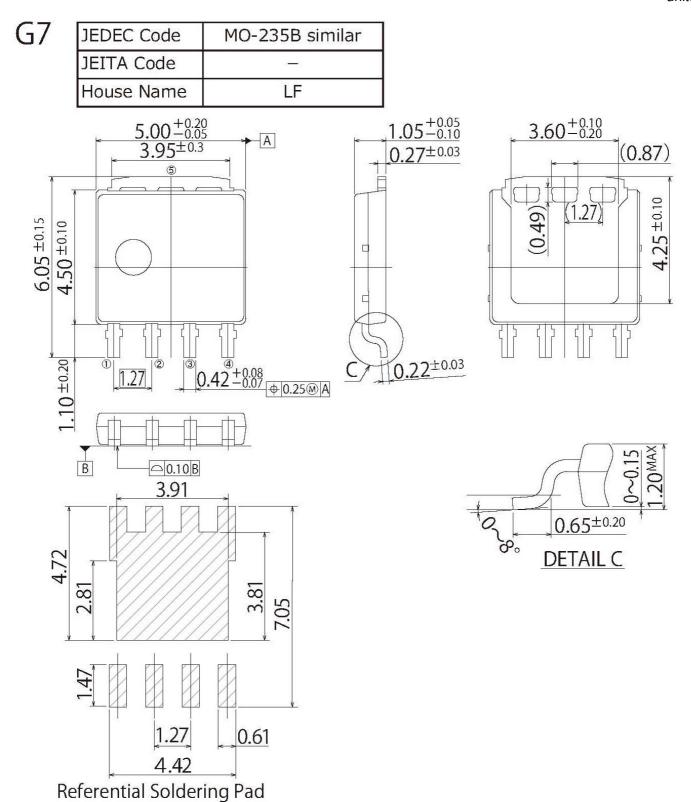








unit:mm



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